

ENERGIES AND RELATIVE INTENSITIES OF 2201, 2490, AND 2508 keV  $\gamma$  LINES IN THE SPECTRUM OF Ga<sup>72</sup>

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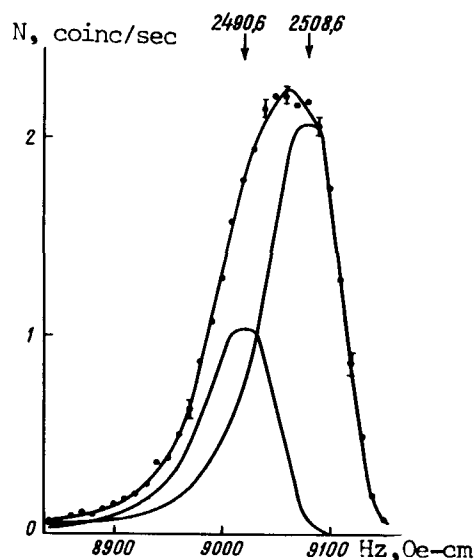
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The Ga<sup>72</sup>  $\gamma$ -ray spectrum was investigated in detail by Johns et al. [1], using the photoelectrons and a double-focusing spectrometer, and by Vitman et al. [2] using the recoil electrons and the VNIIM (Metrology Institute) elotron. However, the intensities given in the two papers for the strong hard lines differ by 20 - 60%, which is way beyond the experimental error. Yet these lines are suitable for energy and intensity calibration of  $\gamma$  spectrometers.

We measured the 2201, 2490, and 2508 deV lines of Ga<sup>72</sup> with the FTI (Physico-technical Institute) elotron for the purpose of obtaining more accurate values for their energies and intensity. To resolve the 2490 + 2508 keV doublet into its components (see the Figure) we used the shape of the 2201-keV line, since it has already been shown [3] that the line shape is independent of the energy if  $h\nu \geq 1.5$  MeV. Our results are listed in the table, which contains for comparison the results of [1,2] as well as the results of Hedgran and Lind [4]. We see that our intensity values corroborate the results of [2]. The values of the intensities of the hard lines given by Johns et al. [1] are apparently too high.

The 2462-keV line reported in [2] did not show up in our experiments. The existence of a line having this energy appears doubtful.



Energies and relative intensities of the 2201, 2490, and 2508 keV lines of Ga<sup>72</sup>

Our data		Hedgran and Lind [4]		Johns et al. [1]		Vitman et al. [2]	
E, keV	I <sub>rel</sub>	E, keV	E, keV	I <sub>rel</sub>	E, keV	I <sub>rel</sub>	
2201.3 ± 0.6	100		2201	100	2205 ± 4	100	
2490.6 ± 1.8	25.4 ± 1.7	2491 ± 3	2490	33.4	2490 ± 5	23.8 ± 2.2	
2508.6 ± 1.0	50.5 ± 1.6	2508 ± 2	2508	56.5	2508 ± 5	51.7 ± 3.3	

[1] Johns, Chidley, and Williams, Phys. Rev. 99, 1645A (1955).

[2] Vitman, Voinova, and Dzheleпов, Izv. AN SSSR ser. fiz. 27, 249 (1963), transl. Bull. USSR Acad. Sci. Phys. Ser. 27, 261 (1963).

[3] Sergeev, Voinova, Dzheleпов, Kalinichev, and Kaminker, PTE No. 5, 1965.

[4] A. Hedgran and D. Lind, Arkiv. fys. 5, 177 (1952).

EFFECT OF SPIN ON THE LONGITUDINAL MAGNETORESISTANCE IN INDIUM ANTIMONIDE AT 4.2°K

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The effect of spin on the longitudinal magnetoresistance for a degenerate electron gas with the carriers scattered by ionized impurities was considered theoretically by A. L. Efros [1]. He has shown that whenever

$$\zeta = h\Omega(N + \frac{1}{2}) + S\mu H \quad (N = 1, 2, \dots) \quad (1)$$

the component  $\sigma_{zz}$  of the conductivity tensor has sharp minima, and the experimentally measured quantity  $\rho_{zz} = 1/\sigma_{zz}$  has sharp maxima. Here  $\mu$  is the spin moment of the electron,  $N$  the principal quantum number,  $\zeta$  the chemical potential,  $\Omega = eH/m^*c$  the Larmor frequency, and  $S = \pm 1$ . Thus, as in the transverse magnetoresistance, the spin should lead to doubling of the maxima. If the spin does not flip during the scattering process then, according to [1], no zeroth maximum  $0^+$  should be observed. The conditions for experimental observation of the influence of spin splitting of the Landau levels on the quantum oscillations of the resistance in a longitudinal magnetic field are the same as in a transverse field. We have observed earlier [2] the influence of spin splitting of the Landau levels on the transverse magnetoresistance in InSb.

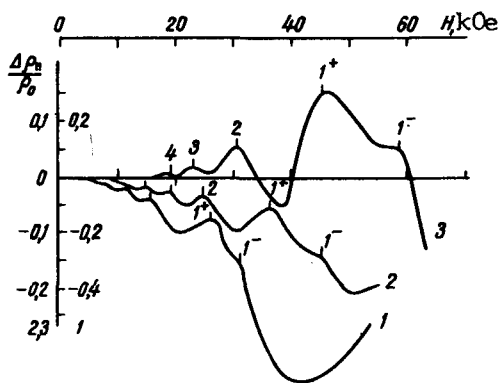


Fig. 1. Plot of  $\Delta\rho_{\parallel}/\rho_0(H)$  for samples 1 - 3.

$\Delta\rho_{\perp}/\rho_0(H)$  curve for the same sample. The bars in Figs. 1 and 2 mark the positions of the experimentally observed maxima, while the indices  $0^+$ ,  $1^-$ ,  $1^+$ , 2, etc. indicate the numbers of the maxima.

It is seen from Figs. 1 and 2 that the first maxima split into  $1^+$  and  $1^-$ . Comparison with the transverse oscillations in the same samples show that the positions of the longitudinal and transverse maxima for  $N = 1, 2$ , etc. coincide quite satisfactorily.

In this paper we present experimental evidence of the influence of the spin on the quantum oscillations of the longitudinal magnetoresistance in indium-antimonide samples at 4.2°K. The results of measurements of  $\Delta\rho_{\parallel}/\rho_0(H)$  for samples 1 - 3 are shown in Fig. 1 ( $1 - n = 4 \times 10^{16} \text{ cm}^{-3}$ ,  $2 - n = 7.35 \times 10^{16} \text{ cm}^{-3}$ ,  $3 - 9.6 \times 10^{16} \text{ cm}^{-3}$ ). To identify the maxima, the measurements were made up to magnetic field values for which the oscillations vanished and  $\Delta\rho_{\parallel}/\rho_0(H)$  varied monotonically. Figure 2 shows the  $\Delta\rho_{\parallel}/\rho_0(H)$  curve for sample No. 3. The same figure shows for comparison the